

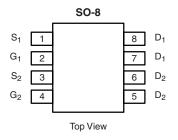
SPN9926S8RGB-VB Datasheet Dual N-Channel 20-V (D-S) MOSFET

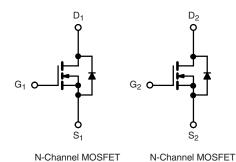
| PRODUCT SUMMARY | | | | |
|---------------------|----------------------------------|--------------------|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) | | |
| 20 | 0.019 at V _{GS} = 4.5 V | 7.1 | | |
| | 0.026 at V _{GS} = 2.5 V | 6.0 | | |

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Trench Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC







ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted Symbol Limit Parameter Unit **Drain-Source Voltage** V_{DS} 20 ٧ Gate-Source Voltage V_{GS} ± 12 $T_A = 25 \degree C$ 7.1 Continuous Drain Current (T_J = 150 °C)^a I_D T_A = 70 °C 5.7 А Pulsed Drain Current (10 µs Pulse Width) 40 I_{DM} 1.7 I_S Continuous Source Current (Diode Conduction)^a T_A = 25 °C 2 P_D w Maximum Power Dissipation^a T_A = 70 °C 1.3 Operating Junction and Storage Temperature Range T_J, T_{stg} - 55 to 150 °C

| THERMAL RESISTANCE RATINGS | | | | | |
|--|-------------------|-------|------|--|--|
| Parameter | Symbol | Limit | Unit | | |
| Maximum Junction-to-Ambient ^a | R _{thJA} | 62.5 | °C/W | | |

Notes:

a. Surface Mounted on FR4 board, t \leq 10 s.

| SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted | | | | | | | |
|--|---------------------|--|-----|-------|-------|------|--|
| Parameter | Symbol | Test Conditions Min. | | Тур. | Max. | Unit | |
| Static | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ | 0.6 | | 1.5 | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 12 V$ | | | ± 100 | nA | |
| Zero Gate Voltage Drain Current | I _{DSS} | $\frac{V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}}{V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 \text{ °C}}$ | | 1 | | | |
| | | | | | 5 | μΑ | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \!\geq\! 5$ V, V_{GS} = 4.5 V | 20 | | | А | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | $V_{GS} = 4.5 \text{ V}, \text{ I}_{\text{D}} = 7.1 \text{ A}$ | | 0.019 | | Ω | |
| | | $V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 6.0 \text{ A}$ | | 0.026 | | | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 10 V, I _D = 7.1 A | | 27 | | S | |
| Diode Forward Voltage ^a | V _{SD} | $I_{\rm S} = 1.7$ A, $V_{\rm GS} = 0$ V | | | 1.2 | V | |
| Dynamic ^b | | | | • | | | |
| Total Gate Charge | Qg | | | 9.5 | | nC | |
| Gate-Source Charge | Q _{gs} | V_{DS} = 10 V, V_{GS} = 4.5 V, I_{D} = 7.1 A | | 1.5 | | | |
| Gate-Drain Charge | Q _{gd} | | | 2.5 | | 1 | |
| Gate Resistance | R _g | f = 1 MHz | | 1.6 | 2.7 | Ω | |
| Turn-On Delay Time | t _{d(on)} | | | 10 | | | |
| Rise Time | t _r | V_{DD} = 10 V, R_L = 10 Ω | | 15 | | | |
| Turn-Off Delay Time | t _{d(off)} | $I_D \cong$ 1 A, V_{GEN} = 4.5 V, R_g = 10 Ω | | 38 | | ns | |
| Fall Time | t _f | | | 25 | | | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 1.7 A, dl/dt = 100 A/μs | | 26 | | | |

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

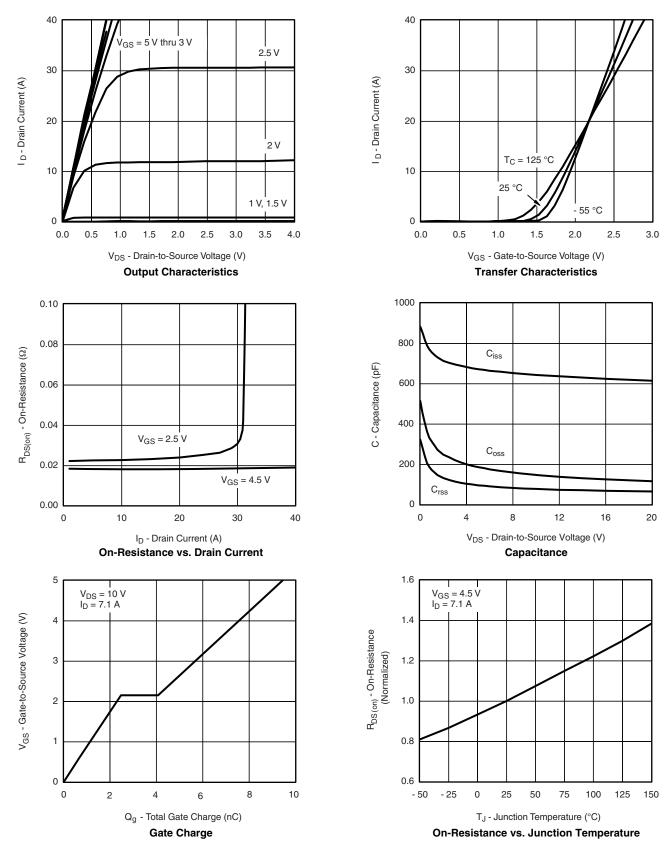
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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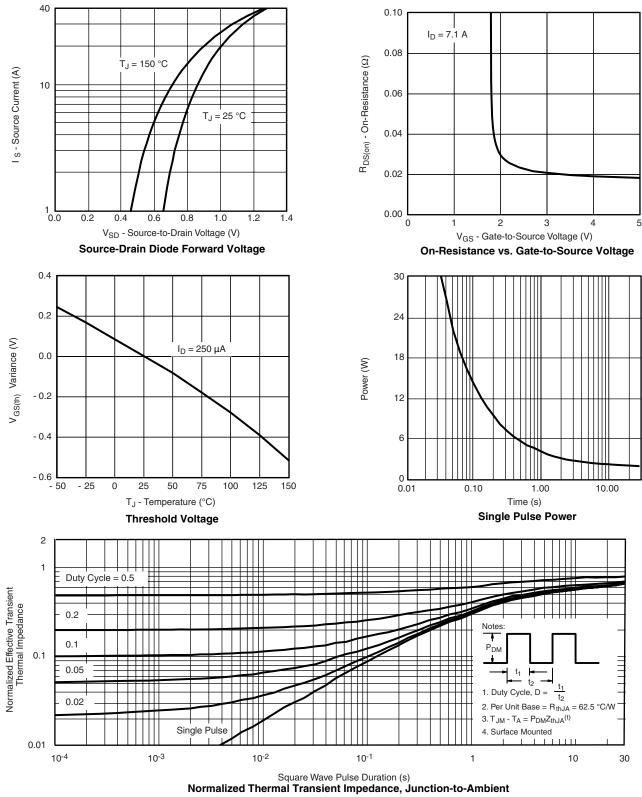


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





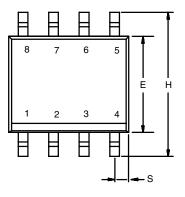
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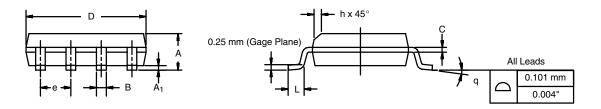




SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012

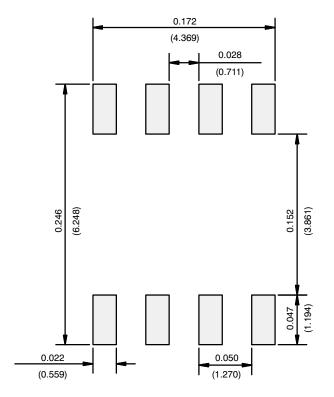




| | MILLIM | IETERS | INCHES | | |
|---|----------|--------|-----------|-------|--|
| DIM | Min | Мах | Min | Max | |
| A | 1.35 | 1.75 | 0.053 | 0.069 | |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 | |
| В | 0.35 | 0.51 | 0.014 | 0.020 | |
| С | 0.19 | 0.25 | 0.0075 | 0.010 | |
| D | 4.80 | 5.00 | 0.189 | 0.196 | |
| E | 3.80 | 4.00 | 0.150 | 0.157 | |
| е | 1.27 BSC | | 0.050 BSC | | |
| н | 5.80 | 6.20 | 0.228 | 0.244 | |
| h | 0.25 | 0.50 | 0.010 | 0.020 | |
| L | 0.50 | 0.93 | 0.020 | 0.037 | |
| q | 0° | 8° | 0° | 8° | |
| S | 0.44 | 0.64 | 0.018 | 0.026 | |
| ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498 | | | | | |



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)



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